SN54BCT29862B, SN74BCT29862B 10-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS SCBS014B – NOVEMBER 1988 – REVISED NOVEMBER 1993

- BiCMOS Design Substantially Reduces Standby Current
- Functionally Equivalent to 'ALS29862 and AMD Am29862A
- Power-Up High-Impedance State
- ESD Protection Exceeds 2000 V Per Mil-STD-883C, Method 3015
- Package Options Include Plastic Small-Outline (DW) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic and Ceramic 300-mil DIPs (JT, NT)

description

These 10-bit bus transceivers are designed for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing.

These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic levels at the output-enable (OEBA and OEAB) inputs.

The outputs are in the high-impedance state during power-up and power-down conditions. The outputs remain in the high-impedance state while the device is powered-down.

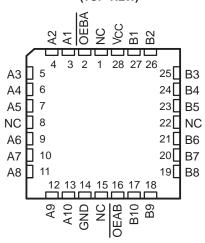
The SN54BCT29862B is characterized for operation over the full military temperature range of -55° C to 125° C. The SN74BCT29862B is characterized for operation from 0°C to 70°C.

	•	,	
OEBA [1	U ₂₄	V _{cc}
A1 [2	23	B1
A2 [3	22	B2
A3 [4	21	B3
A4 [5	20	B4
A5 [6	19	B5
A6 [7	18	B6
A7 [8	17	B7
A8 [9	16	B8
A9 [10	15	В9
A10 [11	14	B10
GND [12	13	OEAB

SN54BCT29862B ... JT OR W PACKAGE

SN74BCT29862B... DW OR NT PACKAGE (TOP VIEW)

SN54BCT29862B ... FK PACKAGE (TOP VIEW)



NC-No internal connection

I ONOTION INDEE								
INP	UTS	OPERATION						
OEAB	OEBA	OPERATION						
L	Н	A to B						
н	L	B to A						
н	Н	Isolation						
L	L	Latch A and B $(A = \overline{B})$						

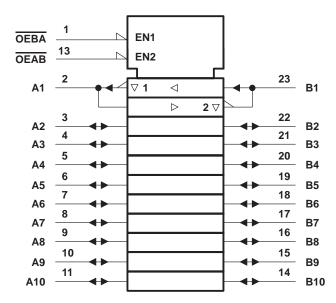
FUNCTION TABLE

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

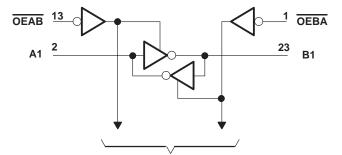
SN54BCT29862B, SN74BCT29862B 10-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

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logic symbol[†]



logic diagram (positive logic)



To Nine Other Channels

[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

Pin numbers shown are for the DW, JT, NT, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[‡]

Supply voltage, V _{CC}	
Input voltage (I/O ports) (see Note 1)	
Input voltage (excluding I/O ports) (see Note 1)	
Voltage applied to any output in the high state	-0.5 V to V _{CC}
Input clamp current	
Current into any output in the low state: SN54BCT298	62B 48 mA
SN74BCT298	62B 96 mA
Operating free-air temperature range: SN54BCT298	62B −55°C to 125°C
SN74BCT298	62B 0°C to 70°C
Storage temperature range	65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input negative voltage rating may be exceeded if the input clamp current rating is observed.

recommended operating conditions

		SN54BCT29862B			SN74BCT29862B			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
VIL	Low-level input voltage			0.8			0.8	V
IIK	Input clamp current			-18			-18	mA
ЮН	H High-level output current -1		-12			-24	mA	
IOL	Low-level output current			24			48	mA
TA	Operating free-air temperature	-55		125	0		70	°C



SN54BCT29862B, SN74BCT29862B **10-BIT BUS TRANSCEIVERS** WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEOT	TEST CONDITIONS		SN54BCT29862B			SN74BCT29862B			
		1231			TYP†	MAX	MIN	TYP†	MAX	UNIT	
VIK		V _{CC} = 4.5 V,	lj = - 18 mA			-1.2			-1.2	V	
V.			I _{OH} = -12 mA	2.4	3.3		2.4	3.3		v	
VOH		$V_{CC} = 4.5 V$	$I_{OH} = -24 \text{ mA}$				2	3.1		V	
Vei			I _{OL} = 24 mA		0.35	0.5				v	
VOL		$V_{CC} = 4.5 V$	I _{OL} = 48 mA				0.35	0.5	v		
Ц		V _{CC} = 5.5 V,	VI = 5.5 V			0.1			0.1	mA	
Control inputs		\/. 07\/			20			20			
lιΗ	A or B port‡	V _{CC} = 5.5 V,	V ₁ = 2.7 V			70			70	μA	
lu.	Control inputs					-0.2			-0.2	mA	
۱IL	A or B port [‡]	V _{CC} = 5.5 V,	V _I = 0.5 V		-0.2		-		-0.2	mA	
IIO(off)	§	$V_{CC} = 0,$	V _O = 2.7 V			0.1			0.1	mA	
los¶		V _{CC} = 5.5 V,	VO = 0	-75		-250	-75		-250	mA	
			Outputs high		20	32		20	32		
lcc	$V_{CC} = 5.5 V$	Outputs low		29	46		29	46	mA		
			Outputs disabled		6.5	11		6.5	11		
Ci		V _{CC} = 5 V,	VI = 0.5 V or 2.5 V		6			6		pF	
Co		V _{CC} = 5 V,	VI = 0.5 V or 2.5 V		8			8		рF	

[†] All typical values are at V_{CC} = 5 V, T_A = 25°C. [‡] For I/O ports, the parameters I_{IH} and I_{IL} include the off-state output current. [§] I_{O(off)} = Power-off bus leakage current [¶] Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, C _L = 50 pF, R1 = 500 Ω, R2 = 500 Ω, T _A = 25°C		C R R	L = 50 pF 1 = 500 Ω 2 = 500 Ω A = MIN to	<u>)</u> ,		UNIT		
			MIN	TYP	MAX	MIN	MAX	MIN	MAX		
^t PLH	A or B	B or A	1	3.6	5.2	1	6.5	1	6.1	ns	
^t PHL		BUIA	0.5	2.4	4.6	0.5	7.5	0.5	4.8	115	
^t PZH		OE	A or B	2.5	5.3	7.2	2.5	9.1	2.5	8.4	ns
^t PZL	ÛE	A OF B	4.5	8	10.6	4.5	13.9	4.5	12.5	115	
^t PHZ	OE	E A or B	2.3	4.8	7.6	2.3	8.4	2.3	8.4	ns	
^t PLZ	UE	AUB	2.3	5.2	7	2.3	9.1	2.3	8.2	115	

[#] For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating condtions. NOTE 2: Load circuits and voltage waveforms are shown in Section 1.





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